
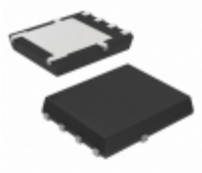
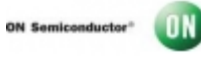
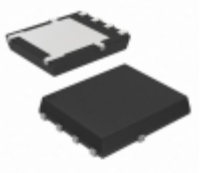
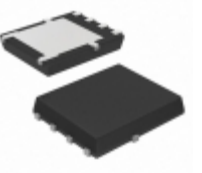
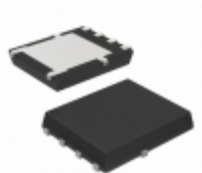
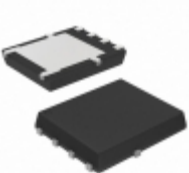

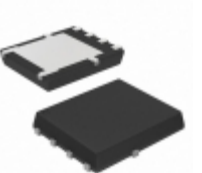
	<h2>NTMFS4852NT1G</h2>
	<p>Hersteller-Teilenummer: NTMFS4852NT1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 16A SO8FL</p> <p>Datenblätter:  NTMFS4852NT1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 3420 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTMFS4852NT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 16A SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	3420 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN, 5 Leads
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Verlustleistung (max)	900mW (Ta), 86.2W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	16A (Ta), 155A (Tc)
Rds On (Max) @ Id, Vgs	2.1 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	71.3nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	4970pF @ 12V
Verpackung	Tape & Reel (TR)

NTMFS4852NT1G ist neu im Original, Suche NTMFS4852NT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMFS4852NT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMFS4852NT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTMFS4851NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 9.5A SO-8FL</p>	 <p>NTMFS4854NST1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 15.2A SO-8FL</p>	 <p>NTMFS4849NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 10.2A SO-8FL</p>	 <p>NTMFS4847NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 11.5A SO-8FL</p>
 <p>NTMFS4849NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 10.2A SO-8FL</p>	 <p>NTMFS4851NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 9.5A SO-8FL</p>	 <p>NTMFS4897NF ON NTMFS4897NF ON</p>	 <p>NTMFS4852NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 16A SO8FL</p>

heiße Teile

Mehr

NTMFS4709NT1G	NTMFS4709NT3G	NTMFS4744NT1G	NTMFS4821NT1G	NTMFS4823NT1G
NTMFS4833NT1G	NTMFS4834N	NTMFS4834NT1G	NTMFS4835N	NTMFS4835NT1G
NTMFS4837NHT1G	NTMFS4837NHT3G	NTMFS4837NT1G	NTMFS4839NHT1G	NTMFS4841NHT1G
NTMFS4841NHT3G	NTMFS4841NT1G	NTMFS4845NT1G	NTMFS4846	NTMFS4846NT1G
NTMFS4847N	NTMFS4847NAT1G	NTMFS4847NT1G	NTMFS4849NT1G	NTMFS4851NT1G
NTMFS4898NFT1G	NTMFS4899NFT1G	NTMFS4921NT1G	NTMFS4921NT3G	NTMFS4923NET1G
NTMFS4925NT1G	NTMFS4925NT3G	NTMFS4926NT1G	NTMFS4927NT1G	NTMFS4933NT1G
NTMFS4934NT1G	NTMFS4935N	NTMFS4935NT1G	NTMFS4936N	NTMFS4936NT1G
NTMFS4937N	NTMFS4937NT1G	NTMFS4939NT1G	NTMFS4939NT3G	NTMFS4941NT1G
NTMFS4943NT1G	NTMFS4945NT1G	NTMFS4946N	NTMFS4946NT1G	NTMFS4955NT1G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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